Electrical conductivity and viscosity of cryolite electrolytes for solar grade silicon (Si-SoG) electrowinning

Michal KORENKO¹, Zuzana VASKOVÁ¹, František ŠIMKO¹, Michal ŠIMURDA¹, Marta AMBROVÁ², Zhong-ning SHI³

1. Institute of Inorganic Chemistry, Slovak Academy of Sciences, Dúbravská cesta 9, SK–84536 Bratislava, Slovakia;
2. Institute of Inorganic Chemistry, Technology and Materials, Slovak University of Technology, Radlinskeho 9, SK–81237, Bratislava, Slovakia;
3. School of Materials and Metallurgy, Northeastern University, Shenyang 110819, China

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Abstract: Electrical conductivity of molten binary and ternary mixtures based on the system NaF−AlF₃−SiO₂ was investigated by means of a tube–cell (made of pyrolytic boron nitride) with stationary electrodes. Viscosity of the binary system Na₃AlF₆−SiO₂ was measured by computerized torsion pendulum method. It was found that conductivity and viscosity varied linearly with temperature in all investigated mixtures. Obtained content dependence of electrical conductivity (isotherms) was divided into two parts. First, one represented the content region up to 10% (mole fraction) of SiO₂; second, the region was with a higher content of SiO₂ from 10% up to 40%. While the conductivity considerably decreased with content of SiO₂ in the second part; it surprisingly rose in the low content range. A small addition of SiO₂ to the molten cryolite (up to 10%) could slightly increase viscosity, but had no influence on the slope of this dependence since it is responsible for a glassy-networks formation in the melt. Further addition of SiO₂ to the molten cryolite had a huge effect on the viscosity.

Key words: electrical conductivity; viscosity; solar grade silicon; molten salts; molten cryolite–silica melts

1 Introduction

Solar power is the most abundant form of renewable energy. It is not yet clear as to what portion of our energy will ultimately be solar-based, although it has the potential to far exceed the total energy demand of the globe. One of the current hurdles against solar energy becoming a major contributor to the energy basket is its high cost. Silicon, being the chief photovoltaic material, accounts for 25%−50% of the cost of solar arrays [1], thus an increasing attention has been paid to the generation of a so-called solar grade silicon (Si-SoG) at low cost. Even though prices of solar-cell modules keep on decreasing, it is still not cheaper in comparison with conventional ways of generating electricity, e.g. fossil fuel or nuclear generation.

High price of Si-SoG caused by limited supply has thus become the bottlenecks of the photovoltaic industry to achieve its much anticipated growth. It is therefore essential to develop a method for the synthesis of Si-SoG which is efficient energy and will deliver inexpensive feedstock material. As a promising approach, the electrodeposition of silicon from fluoride-based electrolytes at a relatively low temperature (1000 °C), similar method to Hall–Héroult process for Al production has been investigated by different researchers [2–13].

Previous examinations of several molten salt electrolytes have revealed that cryolite-based salts could be suitable for the electrolysis of silicon with respect to the product purity and current efficiency [7,8]. Nevertheless, the process has not been commercialized successfully to date due to one major problem: the high melting point of Si (1412 °C), which prevents formation of liquid silicon at the typical electrolysis temperature of 1000 °C. Moreover, a detailed knowledge of the physico-chemical properties of the different cryolite-based electrolytes is also very limited [6,10,14–16].

The present work is a part of larger project...
undertaken to obtain the primary physico-chemical properties like density, viscosity, electrical conductivity, vapour pressure and surface properties of different fluoride melts (containing silicon species), mainly based on cryolite (Na$_3$AlF$_6$)–silica(SiO$_2$) systems. The final object is thus to obtain the base for a physico-chemical description of molten electrolytes needed for the future electrowinning of Si-SoG.

Viscosity and particular electrical conductivity of the electrolytes have a primary importance for any electrochemical applications. Besides the mentioned above, some consideration on structure and transport theories of electrolytes may be also tested by means of these data. Although the physico-chemical properties of different molten cryolite systems are a subject of a long-term research due to the Hall–Héroult technology, data concerning the electrical conductivity and viscosity of the specific system Na$_3$AlF$_6$–SiO$_2$ are rather rare [6,14,15].

2 Experimental

Synthetic cryolite (NaF–AlF$_3$ of eutectic composition) was used for the preparing of the samples (AlF$_3$ sublimated under low pressure (ca. 100 Pa) at 1100 °C). Analytical grade compounds like NaF (Fluka™) and SiO$_2$ (Johnson Mathey Chemicals™, U.K.) were used. For determination of the cell constant specpure NaCl and electrode consisted of a platinum − platinum alloy (10 % rhodium) rod (1 mm outer diameter) in a fixed position inside the pBN capillary. A melt container (crucible made of the same alloy) was served as a counter electrode. Crucible containing ca. 35 g of salt mixture was placed in a closed vertical laboratory furnace under the inert argon atmosphere with some overpressure. The pBN capillary, with the platinum–rhodium electrode inside, was moved up and down to the top of the cylinder. The depth of immersion was controlled using the electrical contact. The whole melting device, including the furnace temperature was controlled by computer. After all the input data and the required temperature profile were inserted, the measurement of the viscosity at the desired temperatures was performed automatically. The experimental error in the viscosity measurement did not exceed 2.5%.

3 Results and discussion

A possibility of the chemical reactions in the melt containing Na$_3$AlF$_6$–SiO$_2$ is of crucial importance in regard to reproducibility of the measurements performed in this system. According to ABRAMOV et al [19] and BELYAЕV et al [20], silica reacts with AlF$_3$ and Na$_3$AlF$_6$ under the formation of SiF$_4$:

$$2\text{SiF}_4(g)+4\text{NaF}(diss)\leftrightarrow2\text{Al}_2\text{O}_3(diss)$$ (1)
$$4\text{AlF}_3(diss)+3\text{SiO}_2(diss)\leftrightarrow3\text{SiF}_4(g)+2\text{Al}_2\text{O}_3(diss)$$ (2)
$$2\text{Na}_3\text{AlF}_6(l)+2\text{SiO}_2(diss)\leftrightarrow2\text{SiF}_4(g)+4\text{NaF}(diss)+2\text{NaAlO}_2(diss)$$ (3)
$$2\text{NaAlO}_2(diss)+2\text{SiO}_2(diss)\leftrightarrow$$
$$\text{Na}_2\text{O}\cdot\text{Al}_2\text{O}_3\cdot2\text{SiO}_2(diss)$$ (4)

Changes in the Gibbs free energy corresponding to these reactions are pretty small [6] ($\Delta G_{f026}^\circ=77.82$ kJ; $\Delta G_{f026}^\circ=4.35$ kJ). Regarding to the thermodynamic probability of reactions (1) and (2), MONNIER and BARAKAT [21], as well as WEILL and FYFE [16] assumed that rates of the above mentioned reactions are fairly small and a change in the composition of the melt is negligible.
On the other hand, mechanism proposed by MONNIER and BARAKAT [21] resulted in the dissociation into Si$^{4+}$ and O$_2^{-}$ ions. However, it seems to be fairly reasonable to assume that SiO$_2$ dissolved in cryolite will form some types of complex anions that could substantially reduce activity of silicon in the melt [6]. Moreover, FELLNER and MATIAŠOVSKÝ [22] later reported chemical investigations in the molten system Na$_3$AlF$_6$–SiO$_2$–Al$_2$O$_3$–AlF$_3$. It was found that the components of this system reacted under the formation of SiF$_4$ that resulted in the mass loss during experiments.

As can be seen in Fig. 1 the conductivity in all of the investigated mixtures varied linearly with the temperature within the limits of error. Slope of the temperature dependence was the same for all mixtures, except for the last mixture (46.67% Na$_3$AlF$_6$+50%AlF$_3$+3.33% SiO$_2$, mole fraction). An addition of silica to cryolite had in general negative effect on the electrical conductivity of cryolite melts, except for the lower content of silica (5% and 10%, mole fraction). In Fig. 1, an influence of AlF$_3$ addition on conductivity of the cryolite–silica systems is shown as well. Cryolite systems containing AlF$_3$ are considered a main constituent for a new so-called acidic electrolyte in the Hall-Héroult process [23−25]. A main reason to measure an influence of SiO$_2$ on the conductivity of acidic cryolite melts is to verify if a small addition of SiO$_2$ will have a similar (positive) effect on the conductivity like in the case of non-acidic cryolite melts. As can be seen from Fig. 1, the small addition of SiO$_2$ (3.33%, mole fraction) decreases conductivity of the acidic cryolite melt (cryolite with higher concentration of AlF$_3$).

Transport properties of mixtures are usually presented in the diagrams showing isotherms. The conductivity of the investigated systems as a function of the content of SiO$_2$ is shown in Fig. 2 (the binary systems based on Na$_3$AlF$_6$–SiO$_2$). As can be seen from Fig. 2, the isothermal dependency can be divided into two parts. First one represents the region up to 10% of SiO$_2$, and the second one is the region with composition from 10% to 40% (and probably more) of SiO$_2$. While the conductivity considerably decreases with the concentration of SiO$_2$ in the second part according to BELYAEV [14], GRJOTHEIM et al [7] and SOKHANVARAN et al [15], it surprisingly slightly rises with concentration of SiO$_2$ in the low concentration range. This trend of conductivity isotherms (at small concentration of SiO$_2$) is not in agreement with the previous works.

In general, the deviation in certain values of electrical conductivity is in the case of GRJOTHEIM et al [6] up to ca. 6%, in the case of BELYAEV [14] up to ca. 20%, in the case of HÍVEŠ et al [24] up to ca. 5%, and in the case of SOKHANVARAN et al [15] up to ca. 20%. Electrical conductivity of pure cryolite as well as cryolite–silica mixtures mostly differs from that measured by BELYAEV [14] and SOKHANVARAN et al [15]. The difference between this work and literature data can be generally explained by the difference between experimental procedures. Needless to say, sufficiently insulated and inert materials (such as pyrolytic boron nitride) were not available [14,7]. Moreover, an experimental value of the electrical conductivity of pure cryolite (at 1000 °C) reported by SOKHANVARAN et al [15] is very low (ca. 2.42 S/cm) compared with the value of other authors, e.g., for pure cryolite, it is (2.80±0.02) S/cm [23−26]. Likewise, the melting point of pure cryolite (998.3±2) °C, mentioned
in Ref. [15], shows considerable deviation from the most cited value of 1011.6 °C [23].

The most interesting point of the present study is that the electrical conductivity of molten cryolite slightly increases with the small addition of silica (up to 10% of SiO$_2$). This surprising behaviour is likely caused by the reaction between molten cryolite and silica (reactions 2, 3 and 4) under the formation of NaF [19,20,22]. This means that the small addition of silica to the molten cryolite a little bit changes so-called cryolite ratio (CR) which is the mole ratio of NaF to AlF$_3$, thus a pure cryolite occurs at the ratio of 3. It is generally accepted that the shift in CR extremely affects the electrical conductivity of the molten cryolite (for CR=1, ca. 1.2 S/cm; for CR=3, ca. 2.8 S/cm; and for CR=9, ca. 4.2 S/cm) [26]. Thus, a small addition of silica to the molten cryolite could (in this way) slightly increase the electrical conductivity. Further addition of silica to the molten cryolite has, however, a negative effect on the conductivity, since it is responsible for a glassy-networks formation in the melt and is accompanied by a substantial increase of viscosity and thus degradation of the transport properties (see Fig. 3).

Fig. 3 Viscosity of mixture Na$_3$AlF$_6$–SiO$_2$

This assumption is also indirectly supported by the results obtained in acidic cryolite melts (Na$_3$AlF$_6$–SiO$_2$–AlF$_3$ system, see Fig. 1). As can be seen from Fig. 1, a small addition of SiO$_2$ to the acidic cryolite has no positive influence on the conductivity like it is in the case of pure cryolite. Silica could react with AlF$_3$ without the formation of NaF (reaction (1)). A possible formation of NaF (by reactions (2), (3) or (4)) is moreover buffered by the presence of a huge amount of AlF$_3$ in the melt that results in the retention of CR in the acidic melt.

Figure 3 shows the experimental results of the viscosity measurement in the Na$_3$AlF$_6$–SiO$_2$ system. These results are shown in the form of relationship between viscosity and temperature at different contents of silica in cryolite. It also shows the values of the viscosity of pure cryolite from previous works [27,28]. The results are in good agreement.

As can be seen from Fig. 3, the viscosity in all investigated mixtures varies linearly with the temperature within the limit of error. Slope of the temperature dependence is the same only in a small content of silica (ca. up to 10% SiO$_2$). At higher contents, the slope linearly varies with the content of silica in molten cryolite. A small addition of silica to the molten cryolite (up to 10%) could slightly increase viscosity, but has no influence on the slope of this dependence. Further addition of silica to the molten cryolite has, however, great effects on the viscosity, since it is responsible for a glassy-network formation in the melt. Higher addition of silica has even the influence on the slope of the temperature dependence of viscosity.

4 Conclusions

1) The electrical conductivity and viscosity vary linearly with temperature in all investigated mixtures of the Na$_3$AlF$_6$–SiO$_2$ system. Slope of the temperature dependence is in the case of electrical conductivity, the same for all of the investigated mixtures.

2) Addition of AlF$_3$ to this system decreases the electrical conductivity. While the conductivity considerably decreases with content of SiO$_2$ in the second part, and it surprisingly slightly rises with the content of SiO$_2$ in the low content range. This behavior is likely caused by the reaction between molten cryolite and silica under the formation of NaF, which changes the cryolite ratio in the melt and thus affects the conductivity.

3) Further addition of silica has a negative effect on the conductivity, since it is responsible for a glassy-network formation in the melt and is accompanied by a substantial increase of viscosity and thus degradation of the transport properties.

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References


关键词: 剧变化。

摘  要: 以热解碳化硼管作电极，用固定电极池常数法研究由 NaF–AlF3–SiO2 构成的二元系和三元系熔盐的电导率;用扭摆法测定 Na2AlF6–SiO2 二元系的黏度。研究发现，所研究熔盐体系的电导率和黏度均与温度呈直线关系。Na2AlF6–SiO2 二元系的电导率与 SiO2 含量关系曲线可分为 0~10%和 10%~40% (摩尔分数)两段，当 SiO2 含量超过 10%之后，电导率随着 SiO2 含量的增加而快速下降，而当 SiO2 含量小于 10%时，电导率随着 SiO2 含量的增加而缓慢增加。在 SiO2 含量大于 10%的冰晶石熔盐中添加少量的 SiO2，熔盐的黏度增加，但增加的趋势基本相同，这与熔盐中形成玻璃网状结构的离子团有关。当在冰晶石熔盐中继续增大 SiO2 含量到 50%时，黏度发生急剧变化。

关键词: 电导率; 黏度; 太阳能级硅; 熔盐; 冰晶石–氧化硅熔盐

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